Gallium phosphide transfer printing for integrated nonlinear photonics

Maximilien Billet^{1,2,3}, Nicolas Poulvellarie^{1,2,3}, Camiel Op de Beeck^{1,2}, Luis Reis^{1,2,3}, Yoan Léger⁴, Charles Cornet⁴, Fabrice Raineri⁵, Isabelle Sagnes⁵, Konstantinos Pantzas⁵, Grégoire Beaudoin⁵, Gunther Roelkens^{1,2}, Francois Leo³ and Bart Kuyken^{1,2}

¹ Photonics Research Group, Ghent University-IMEC, Ghent, Belgium ² Center for Nano and Biophotonics (NB-Photonics), Ghent University, Ghent, Belgium ³ OPERA-Photonique, Université libre de Bruxelles, Brussels, Belgium ⁴ Université Rennes, INSA Rennes, CNRS, Institut FOTON – UMR 6082, F-35000 Rennes, France ⁵ Centre de Nanosciences et de Nanotechnologies (C2N), CNRS, Université. Paris Sud. Paris Saclay, F-91120 Palaiseau, France

Integrated nonlinear photonics has drawn an increased interest as it provides scalable, compact, and low cost solutions for a large range of applications. Indeed, the high confinement of the light in integrated waveguides allows for enhanced nonlinear effects. However, mature highly nonlinear platforms such as silicon-on-insulator (SOI) circuits suffer from nonlinear losses at telecom wavelengths caused by two-photon absorption. Moreover, the platform lacks a second order nonlinear susceptibility, which is not the case for wide bandgap III-V semiconductors. Recently, gallium phosphide-on-insulator (GaP-OI) has been proposed as an efficient platform for second and third order nonlinear applications [1] and last year we demonstrated as a proof of concept the transfer printing of GaP as a versatile technique for GaP hetero-integration [2].



Fig. 1 (a) Process of GaP transfer printing on an insulator target. The top picture shows a suspended source coupon anchored to the epitaxial substrate via a-Si tethers and the bottom one shows a printed GaP coupon. (b) SEM picture of a microring resonator patterned on a GaP printed coupon (the ring diameter is 30 μ m). (c) Measurement of a microring resonance line.

In this work we show an improved process for GaP transfer printing by using a new design of encapsulated MOCVD-grown GaP coupons allowing for drastically lower propagation losses. Here, hydrogenated amorphous silicon (a-Si) tethers are anchored into the GaP epitaxial substrate. The coupons are patterned, released and printed on an insulator target following the method described in reference [2]. Then, the encapsulation is removed with dry and wet etching and microring resonators are patterned using electron beam lithography and dry etching techniques. The oxide hard mask used for the lithography is chemically etched in a HF solution. Figure 1.(a) shows the result of the printing process. Figure 1.(b) shows a microring patterned on a printed GaP coupon. The resonances of the ring are measured at telecom wavelengths using a continuous wave tunable laser. The best Q-factor extracted from extinction ratio measurements, as shown in Figure 1.(c) for a ring-waveguide of 1 μ m width and 300 nm height, is around 25 000, corresponding to propagation losses of 1.2 dB/mm for the fundamental TE mode [3]. These results pave the way for highly versatile hetero-integration of GaP as a nonlinear material on complex integrated photonic circuits. To prove the efficiency of our platform for nonlinear applications, we will show experimental results of quasiphase-matched (QPM) second harmonic generation (SHG).

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ROOM 7

ROOM 8 factors exceeding 30 millions and

ROOM 9

ROOM 10

Overcoming optical performance

and diffusion issues in thermally

•J. Shields, C. Ruiz de Galarreta, J.

Bertolotti, and C.D. Wright; Col-

lege of Engineering Mathematics and

Physical Sciences, Exeter, United

We experimentally demonstrate

how thermally activated diffusion

can irreversibly degrade the optical

performance of thermally tunable

phase-change material based

metasurfaces to unacceptable levels,

and validate a way to address such a

fundamental issue via incorporating

ultrathin Si3N4 barrier lavers.

tunable phase-change

11:45

EH-5.4 FRI

metasurfaces

Kingdom

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11:45

ROOM 11

in GaAs-based THz-QCLs. We present a novel fabrication-scheme for ZnO/Zn0.88Mg0.12O THz-QCL structures, yielding the first observation of THz-electroluminescence in ZnO.

11:45

CC-7.4 FRI

Terahertz intersubband electroluminescence from n-type germanium quantum wells

•D. Stark¹, M. Mirza², L. Persichetti³, M. Montanari³, S. Markmann¹, M. Beck¹, T. Grange⁴, S. Birner⁴, M. Virgilio⁵, C. Ciano³, M. Ortolani⁶, C. Corley⁷, G. Capellini^{3,7}, L. Di Gaspare³, M. De Seta³, D.J. Paul², J. Faist¹, and G. Scalari¹; ¹Institute for Quantum Electronics, Department of Physics, ETH Zürich, Zürich, Switzerland; ²James Watt School of Engineering, University of Glasgow, Glasgow, United Kingdom; ³Dipartimento di Scienze, Universita Roma Tre, Roma, Italy; ⁴nextnano GmbH, München, Germany; ⁵Dipartimento di Fisica "E. Fermi," Universita di Pisa, Pisa, Italy; ⁶Sapienza University of Rome, Department of Physics, Rome, Italy; ⁷IHP - Leibniz-Institut für innovative Mikroelektronik, Frankfurt (Oder), Germany We report the observation of intersubband electroluminescence from

n-type Ge/SiGe quantum cascade structures at THz frequencies. This is an important step towards an integrated THz quantum cascade laser on silicon.

12:00

CC-7.5 FRI

All-Optical Control of Quantum Cascade Random Lasers

Enhanced by Deep Learning •B. Limbacher^{1,2}, S. Schönhuber^{1,2} N. Bachelard³, M.A. Kainz^{1,2}, A.M. Andrews^{2,4}, H. Detz⁵, G. Strasser^{2,4}, J. Darmo^{1,2}, S. Rotter³, and K. Unterrainer^{1,2}; ¹Photonics Institute, TU Wien, Vienna, Austria; ²Center for Micro-and Nanostructures, TU Wien, Vienna, Austria; ³Institute for Theoretical Physics, TU Wien, Vienna, Austria; ⁴Institute for Solid-

ROOM 12

JSIV-3.4 FRI 11:45

Forecasting turbulence in a passive resonator with supervised

Lille, France; ²Universidad de Chile, Santiago, Chile; ³Aston University, Birmingham, United Kingdom Chaotic dynamics implies an exponential magnification of any inaccuracy in the initial conditions. Consequently, long-term forecasting becomes an elusive task. Here, we address the predictability of experimental extreme events through the machine learning.

JSIV-3.5 FRI

Metasurface-based

Daejeon, South Korea

polarizations.

Splitter with Deep Learning

In this study, all-dielectric

metasurface-based beam splitter is

realized by a deep neural network

to split the beam at the angle of

±46.8° and achieve more than 0.97

transmission value for TE and TM

CJ-8.3 FRI

Q-Switched Rod-Type Multicore Fibre Laser Delivering 3.1 mJ Pulses

11:45

•C. Aleshire¹, A. Steinkopff⁴, M. Karst^{1,2}, A. Klenke^{1,2}, C. Jauregui¹, S. Kuhn³, J. Nold³, N. Haarlammert³, T. Schreiber³, and J. Limpert^{1,2,3}; ¹Institute of Applied Physics, Friedrich-Schiller-University Jena, Jena, Germany; ²Helmholtz-Institute Jena, Jena, Germany; ³Fraunhofer Institute for Applied Optics and Precision Engineering, Jena, Germany A custom rod-type multicore Ybdoped fibre is used in Q-switched operation, achieving 3.1 mJ pulse energy. The fibre design, laser performance, and prospects for further

power scaling in multistage MCF

amplifiers will be discussed.

CJ-8.4 FRI

The contribution has been withdrawn.

CK-8.4 FRI 11:45

wafer-level yield.

AlGaAs-on-insulator Waveguides for Highly Efficient Photon Pair Generation

•*H.* Mahmudlu^{1,2,3}, S. May⁴, A. Angulo^{1,2,3}, M. Sorel^{4,5}, and M. Kues^{1,2,3}; ¹Institute of Photonics, Leibniz University Hannover, Hannover, Germany; ²Hannover Centre for Optical Technologies, Leibniz University Hannover, Hannover, Germany; ³Cluster of Excellence PhoenixD (Photonic, Optics, and Engineering - Innovation Across Disciplines), Leibniz University Hannover, Hannover, Germany; ⁴School of Engineering, University of Glasgow, Glasgow, United Kingdom; ⁵Institute of Technologies for Communication, Information and Perception (TeCIP), Sant'Anna School of Advanced Studies, Pisa, Italy

We demonstrate the generation of correlated photon pairs in AlGaAs-on-insulator waveguides through spontaneous four-wave mixing at telecom wavelengths with a generation efficiency of 0.096 × 10^12 pairs/(s×W^2), one of the highest achieved in integrated structures.

12:00

CK-8.5 FRI

12:00

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EE-5.4 FRI

Role of dispersion and compression ratio on the temporal contrast of SPM-broadened post-compressed pulses

•E. Escoto¹, A.-L. Viotti^{1,2}, S. Alisauskas¹, H. Tünnermann¹, M. Seidel¹, K. Dudde¹, B. Manschwetus¹, I. Hartl¹, and C.M. Heyl^{1,3,4}; ¹Deutsches Elektronen-Synchrotron DESY, Hamburg, Germany; ²Department of Physics, Lund University, Lund, Sweden; ³Helmholtz-Institute Jena, Jena, Germany; ⁴GSI Helmholtzzentrum für Schwerionenforschung GmbH, Darmstadt, Germany

We explore the effects of dispersion and compression ratio on pulse post-compression. We show by numerical simulations, supported by experimental data, that ultrashort pulses with high temporal contrast can be produced at high compression ratios.

12:00 EH-5.5 FRI

157 -

Efficient tunable UV pulse generation from a green pumped fs-OPCPA

EE-5.5 FRI

•T. Lang, S. Alisauskas, M. Kazemi, A. Tajalli, and I. Hartl; Deutsches Elektronen-Synchrotron DESY. Hamburg, Germany

We present highly efficient upconversion schemes for broadband SH-pumped OPCPAs. Utilizing the Yb-pump in a cascaded-SFG, 69% conversion efficiencies to 300nm were obtained without degradation. The tunable UV pulses are compressed in glass to 75fs.

12:00 Anomalous Resonance Frequency

Shift in Liquid Crystal-Loaded Metamaterials

•E. Perivolari¹, V. Apostolopoulos¹, M. Kaczmarek¹, and V.A. Fedotov²; ¹Physics and Astronomy, University of Southampton, Southampton, United Kingdom; ²Optoelectronics Research Centre & Centre for Photonic Metamaterials, University of Southampton, Southampton, United Kingdom

We show that Babinet complementary patterns of metamaterials may not exhibit the same frequency tun-





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